Beam Power Tube

T12 NOVAR TYPE

	112 NOVAR 1 YPE							
	$P_b = 30 W$		Overload P _b = 200 W					
	Electrical Characteristics — Bogey Values							
	Heater Voltage, ac or dc	Eh		6.3	V			
	Heater Current	lh		2.3	Α			
	Direct Interelectrode Capacitances:a							
	Grid No. 1 to plate	c _{a1-p}		0.6	рF			
	Input: G1 to (K, G3, G2, H)	ci		22	ρF			
	Output: P to (K, G3, G2, H)	co		11	рF			
	For the following characteristics, see Conditions below:							
	Amplification Factor							
	(Triode Connection) ^b μ	-		3.5 c				
	Plate Resistance (Approx.). rp	_	_	5800	Ω			
	Transconductance gm	_	 	9600	μmho			
	DC Plate Current Ib	_	580 d 40 d	130	mA			
	DC Grid-No. 2 Current I _{c2} Cutoff DC Grid-No. 1	_	400	2.8	mA			
	Voltage for $l_b = 1 \text{ mA} \dots \text{E}_{c1}(c_0)$	-125		_44	V			
	Conditions:	-125	_	-44	V			
	Heater Voltage Eh		 6.3		· v			
	Peak Positive-Pulse		0.5		V			
	Plate Voltage® ebm	5000	_	-	V			
	DC Plate Voltage Eb	_	55	175	V			
	DC Grid-No. 3 Voltage Ec3	0	30	30	V			
	DC Grid-No. 2 Voltage Ec2	125	125	125	V			
	DC Grid No. 1 Voltage Ec1		0	-25	V			
_	Mechanical Characteristics							
	Dimensional Outline JEDEC No. 12-117							
	EnvelopeJEDEC T-12							
	Top Cap Large-Butt							
	JEDEC!							
	Terminal Connections			(SEDEO	19-007			
	(See TERMINAL DIAGRAM)							
	Type of Cathode		Coà	ted Unipo	tential			
	Operating Position	• • • • • •		• • • • • • • •	Any			
	Maximum Ratings — Design-Maximum Values †							
	For operation as a Horizontal-Deflection-Amplifier Tube in a 525-line, 30-frame system.							
_	DC Plate Supply Voltage	Ebb	•	990	V			
	Peak Positive-Pulse Plate Voltage9.			7500	V			
	Peak-Negative-Pulse Plate Voltage			1100	V			
	<u>_</u>		•					

DC Grid-No. 3 Voltageh	E _c 3	75	V				
DC Grid-No. 2 (Screen-Grid) Voltage	E _{c2}	220	V				
Peak Negative-Pulse Grid-No. 1							
(Control-Grid) Voltage	−e _{c1m}	330	V				
Heater-Cathode Voltage:							
Peak	ehkm	±200	V				
Average	Ehk	100	V				
Heater Voltage	Eh	5.7 to 6.9	V	$\overline{}$			
Peak	ikm	1200	mΑ				
Average	lk (av)	350	mΑ				
Grid-No. 2 Input	P _{q2}	5	W				
Plate Dissipation j	Pb	30	W				
Temporary Overload Plate Dissipation \mathbf{k} :	Pb	200	W				
Envelope Temperature (at hottest point							
on envelope surface)	ΤE	250	oC				
Maximum Circuit Values							
Grid-No. 1-Circuit Resistance:	$R_{g(ckt)}$						
Cathode Bias		1.0 me	gohm				
(with min. $R_K = 100 \Omega$							
Grid-leak Bias 10.0 megohms							
(with signal peak clamped to zero bias)							
Fixed Bias 0.47 megohm							
(where positive grid current is not drawn)							
a Measured without external shield in accordance with the current issue of EIA Standard RS-191B.							
b With grid No. 3 and grid No. 2 connected, respectively, to cathode and plate at socket.							
c Conditions: $E_b = E_{c2} = 125 \text{ V}, E_{c1} = -25 \text{ V}.$							
This value can be measured by a method involving a recurrent waveform such that the Maximum Ratings of the tube will not be exceeded.							
e Under pulse-duration condition specified in Footnote g.							
f As defined in the current issue of EIA Standard RS-239A.							

- g This rating is applicable when the duration of the voltage pulse does not exceed 15% of one horizontal scanning cycle. In a 525-line, 30-frame system, 15% of one scanning cycle is 10 μ s.
- h In horizontal-deflection-amplifier service, a positive voltage should be applied to grid No. 3 to reduce interference from "snivets", which may occur in both vhf and uhf television receivers, and to increase power output. A typical value is 30 V.
- j An adequate bias resistor or other means is required to protect the tube in the absence of excitation.
- k Total continuous or accumulated time not to exceed 40 seconds.



TERMINAL DIAGRAM (BOTTOM VIEW)

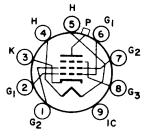
Pin 1 - Grid No. 2

Pin 2 - Grid No. 1 Pin 3 - Cathode

fili 3 - Cathoue

Pin 4 - Heater

Pin 5 - Heater



Pin 6 - Grid No. 1

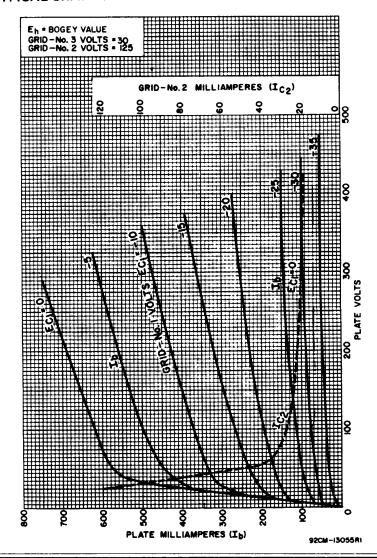
Pin 7 - Grid No. 2

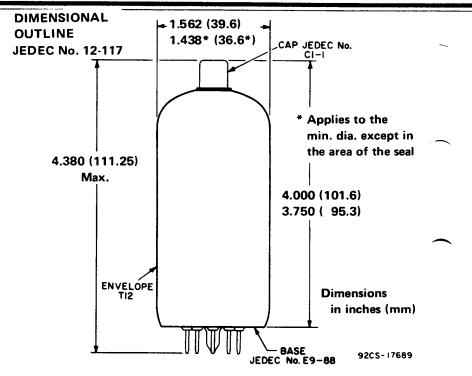
Pin 8 - Grid No. 3

Pin 9 - Do Not Use

Top Cap - Plate

TYPICAL CHARACTERISTICS





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